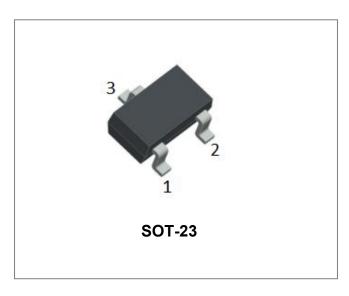






#### SM712 TVS Diode

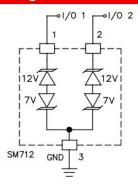


#### Description

The SM712 transient voltage suppressor (TVS) diode is designed for asymmetrical (12V to -7V) protection in multi-point data transmission standard RS-485 applications. The SM712 may be used to protect devices from transient voltages resulting from electrostatic discharge (ESD), electrical fast transients (EFT), and lightning.

The SM712 replaces four discrete components by integrating two 12V and two 7V TVS diodes in a single package. The integrated design aids in reducing voltage over-shoot associated with trace inductance. The low clamping voltage of the SM712 minimizes the stress on the protected transceiver. The SOT23 package allows flexibility in the design of "crowded" circuit boards.

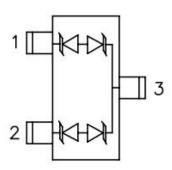
#### **Circuit Diagram**



#### **Features**

- Transient protection for high speed data lines
  IEC 61000-4-2(ESD)±15KV(air),±8KV(contact)
  IEC 61000-4-4(EFT) 40A (5/50ns)
  IEC 61000-4-5(Lightning) 12A (8/20us)
- Protects two +12V to -7V lines
- Low capacitance
- Low clamping voltage
- Solid-state silicon avalanche technology
- "-A" is an AEC-Q101 qualified device

### **Schematic and Pin Configuration**



#### **Mechanical Characteristics**

- SOT-23 package
- Marking: 712
- Molding compound flammability rating: UL 94V-0

#### **Applications**

- Protection of RS-485 transceivers with extended
- common-mode range
- Security systems
- Automatic Teller Machines
- HFC systems
- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







### **Maximum Ratings:**

Characteristics	Symbol	Max.	Units
Peak Pulse Power (tp=8/20us)	P <sub>PK</sub>	300	W
Lead Soldering Temperature	T∟	260(10 seconds)	°C
Operating Temperature	TJ	-55 to +125	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics@T<sub>A</sub>=25°C unless otherwise specified

			_	to 3 a (12V T	nd 2 to VS)		to 1 an		
Characteristics	Symbol	Condition	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Reverse Stand-Off Voltage*	$V_{RWM}$	-	-	-	12	-		7	V
Reverse Breakdown Voltage*	$V_{BR}$	I <sub>PT</sub> =1mA	13.3	-	-	7.5	-	-	V
Reverse Leakage Current*	I <sub>R</sub>	$V_R = V_{RWM}$	-	-	1	-	1	20	uA
Clamping Voltage	Vc	I <sub>PP</sub> =5A, tp=8/20us	-	-	20	-		12	٧
Clamping Voltage	Vc	I <sub>PP</sub> =15A, tp=8/20us	-	-	26	-	_	14	V
Junction Capacitance	Cj	V <sub>R</sub> =0V, f=1MHz	-		75	-	-	75	pF

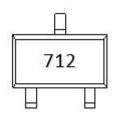
<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

### **Ordering Information**

Device	Package	Shipping	
SM712	SOT-23	3000pcs / reel	
SIVIT 12	(Pb-Free)	3000pcs / reer	
SM712TR	SOT-23	3000pcs / reel	
SIVITIZIN	(Pb-Free)	3000pcs / reer	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Marking Diagram**



712 = Device Code

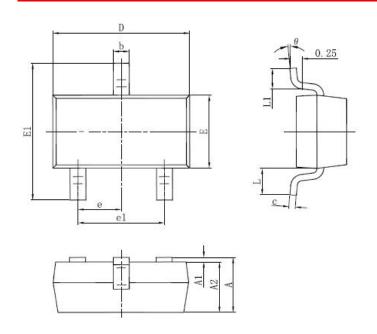
<sup>•</sup> China - Germany - Korea - Singapore - United States •





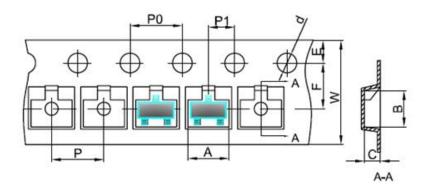


## **Mechanical Dimensions SOT-23**



OVMDOL	Millimeters		Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	0.890	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.076	0.170	0.003	0.007	
D	2.650	3.050	0.104	0.120	
Е	1.190	1.400	0.047	0.055	
E1	2.100	2.550	0.083	0.100	
е	0.950 TYP.		0.037 TYP.		
e1	1.780	2.050	0.070	0.081	
L	0.550 REF.		0.022 REF.		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

## **Carrier Tape Specification SOT-23**



SYMBOL	Millimeters			
STWIBUL	Min.	Max.		
Α	3.05	3.25		
В	2.67	2.87		
С	1.12	1.32		
d	1.40	1.60		
E	1.65	1.85		
F	3.40	3.60		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	7.90	8.30		







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